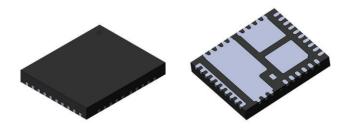


Vishay Siliconix

80 A VRPower[®], Smart Power Stage With Current Sensing and Temperature Monitor



DESCRIPTION

The SiC830 is an integrated power stage solution optimized for synchronous buck applications to offer high current, high efficiency, and high power density performance. Packaged in Vishay's proprietary 5 mm x 6 mm MLP package, SiC830 enables voltage regulator design to deliver in excess of 80 A per phase current.

The internal power MOSFETs utilize Vishay's state-of-the-art TrenchFET[®] Gen IV technology that delivers industry bench mark performance to significantly reduce switching and conduction losses.

The SiC830 incorporates an advanced MOSFET gate driver IC that features high current driving capability, adaptive dead-time control, and integrated bootstrap switch, a thermal monitor that alerts the system of excessive junction temperature. This driver is also compatible with wide range of PWM controllers with the support of both 3.3 V and 5 V PWM logic with tri-state. Diode emulation mode can be enabled at light loads through the use of GLCTRL signal. The device also integrates a current monitor to provide a real time scale down of inductor current (I_{MON}). A temperature monitor provides the system an indication of the power stage internal temperature (T_{MON}) and can be used to throttle the system operation down to a safer level if needed. The device also integrates fault alerts such as HS FET overcurrent, over temperature and HS MOSFET short failures.

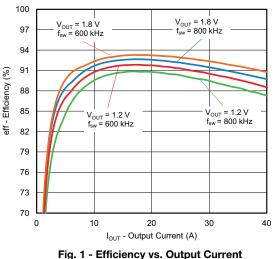
FEATURES

- Thermally enhanced PowerPAK® MLP56-39L package
- Optimize MOSFET switching performance with integrated Schottky diode in LS MOSFET
- Up to 80 A continuous current
- · High frequency operation up to 2 MHz
- Power MOSFETs optimized for 12 V to 19 V input stage and 10 % to 15 % duty cycle operation
- 3.3 V / 5 V PWM logic with tri-state and hold-off
- PWM minimum controllable on time of 30 ns
- Diode emulation mode at light loads for high efficiency over the full load range using GLCTRL pin
- Low PWM propagation delay (< 20 ns)
- Current sense monitor (I_{MON})
- Temperature monitor (T_{MON})
- Over temperature alert
- HS MOSFET over-current and short alert
- Under voltage lockout for V_{DRV} and BOOT
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Synchronous buck converters
- Multi-phase VRDs for CPU, GPU, and memory
- DC/DC VR modules

EFFICIENCY



 $(V_{IN} = 12 \text{ V}, \text{ L} = 150 \text{ nH}, V_{CC} = V_{DRV} = 5 \text{ V})$

1 For technical questions, contact: <u>powerictechsupport@vishay.com</u> Document Number: 77047

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SiC830 Datasheet in Brief

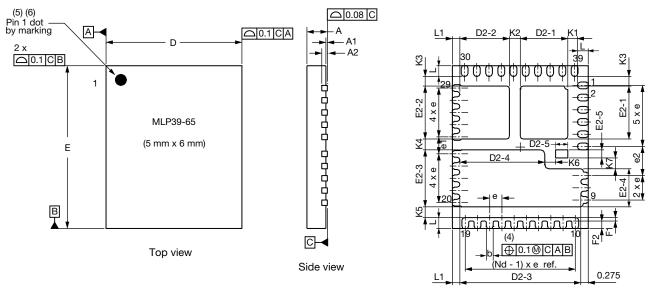
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"For more details, please contact <u>VRPower@vishay.com</u>"



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Bottom view

DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A ⁽⁸⁾	0.65	0.75	0.85	0.026	0.030	0.033	
A1	0.00	-	0.05	0.000	-	0.002	
A2	0.20 ref.			0.008 ref.			
b ⁽⁴⁾	0.20	0.25	0.30	0.078	0.098	0.011	
D	4.90	5.00	5.10	0.193	0.197	0.201	
е	0.450 BSC			0.018 BSC			
e1	0.625 BSC			0.025 BSC			
e2	1.075 BSC			0.042 BSC			
E	5.90	6.00	6.10	0.232	0.236	0.240	
D2-1	1.65	1.75	1.85	0.065	0.069	0.073	
D2-2	1.73	1.83	1.93	0.068	0.072	0.076	
D2-3	4.35	4.45	4.55	0.171	0.175	0.179	
D2-4	3.03	3.13	3.23	0.119	0.123	0.127	
D2-5	0.35	0.45	0.55	0.014	0.018	0.022	
E2-1	1.85	1.95	2.05	0.073	0.077	0.081	
E2-2	1.85	1.95	2.05	0.073	0.077	0.081	
E2-3	2.00	2.10	2.20	0.079	0.083	0.087	
E2-4	1.30	1.40	1.50	0.051	0.055	0.059	
E2-5	0.20	0.30	0.40	0.008	0.012	0.016	
L	0.30	0.40	0.50	0.012	0.016	0.020	
L1	0.18	0.28	0.38	0.007	0.011	0.015	
F1	0.125 BSC			0.005 BSC			
F2		0.275 BSC		0.011 BSC			

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Package Information



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DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
K1	0.35 ref.			0.014 ref.			
K2	0.40 ref.			0.016 ref.			
K3	0.35 ref.			0.014 ref.			
K4	0.40 ref.			0.016 ref.			
K5	0.40 ref.			0.016 ref.			
K6	0.40 ref.			0.016 ref.			
K7	0.40 ref.			0.016 ref.			
N ⁽³⁾	39			39			
Nd ⁽³⁾	10			10			
Ne ⁽³⁾		10		10			
ECN: T19-0106-Re DWG: 6074	ev. C, 08-Apr-2019	9					

Notes

⁽¹⁾ Use millimeters as the primary measurement

⁽²⁾ Dimensioning and tolerances conform to ASME Y14.5M. - 1994

⁽³⁾ N is the number of terminals Nd is the number of terminals in X-direction and Ne is the number of terminals in Y-direction

⁽⁴⁾ Dimension b applies to plated terminal and is measured between 0.20 mm and 0.25 mm from terminal tip

⁽⁵⁾ The pin #1 identifier must be existed on the top surface of the package by using indentation mark or other feature of package body

⁽⁶⁾ Exact shape and size of this feature is optional

⁽⁷⁾ Package warpage max. 0.08 mm

⁽⁸⁾ Applied only for terminals



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